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FAIRCHILD

SEMICONDUCTOR®

December 2008

FDS8882 N-Channel PowerTrench[®] MOSFET 30 V, 9 A, 20.0 m Ω

Features

- Max $r_{DS(on)}$ = 20.0 m Ω at V_{GS} = 10 V, I_D = 9 A
- Max $r_{DS(on)}$ = 22.5 m Ω at V_{GS} = 4.5 V, I_D = 8 A
- High performance trench technology for extremely low r_{DS(on)} and fast switching
- High power and current handling capability
- Termination is Lead-free and RoHS Compliant

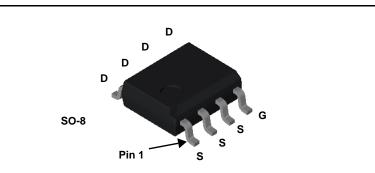


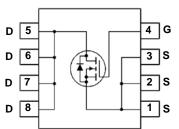
General Description

The FDS8882 has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest $r_{DS(on)}$ while maintaining excellent switching performance.

Applications

- Notebook System Regulators
- DC/DC Converters





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous			9	٨	
D	-Pulsed			21	— A	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	32	mJ	
D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	w	
PD	Power Dissipation	T _A = 25 °C	(Note 1b)	1.0	VV	
T _J , T _{STG}	Operating and Storage Junction Tempe	rature Range		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	50	°C/w

Package Marking and Ordering Information

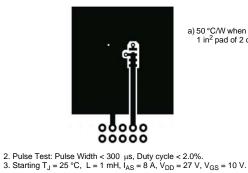
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8882	FDS8882	SO8	13 "	12 mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		4		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \ \mu A$	1.0	1.7	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-6		mV/°C
r _{DS(on)} Static Drain to Source On R		V _{GS} = 10 V, I _D = 9 A		13.2	20.0	
	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 8 \text{ A}$		16.6	22.5	mΩ
		$V_{GS} = 10 \text{ V}, \ I_D = 9 \text{ A}, \text{ T}_J = 125 \text{ °C}$		18.5	28.0	
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 9 A$		36		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			707	940	pF
C _{oss}	Output Capacitance	─ V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		138	185	pF
C _{rss}	Reverse Transfer Capacitance			88	135	pF
R _g	Gate Resistance			1.8		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			7	14	ns
t _r	Rise Time	$V_{DD} = 15 \text{ V}, \text{ I}_{D} = 9 \text{ A},$		3	10	ns
t _{d(off)}	Turn-Off Delay Time	$-V_{GS}$ = 10 V, R _{GEN} = 6 Ω		19	35	ns
t _f	Fall Time			4	10	ns
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		14	20	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V$ $V_{DD} = 15 V,$ $I_{D} = 9 A$		8	11	nC
Q _{gs}	Gate to Source Charge	ID - 9 X		2.2		nC
Q _{gd}	Gate to Drain "Miller" Charge			2.8		nC
Drain-Sou	urce Diode Characteristics					
		V _{GS} = 0 V, I _S = 9 A		0.8	1.2	
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$		0.7	1.2	V
t _{rr}	Reverse Recovery Time	- I _F = 9 A, di/dt = 100 A/μs		17	31	ns
_		$T_{F} = 9 A$, $u/u = 100 A/\mu s$				-

NOTES:

 Q_{rr}

1. R_{01A} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



Reverse Recovery Charge

a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



b) 125 °C/W when mounted on a minimum pad.

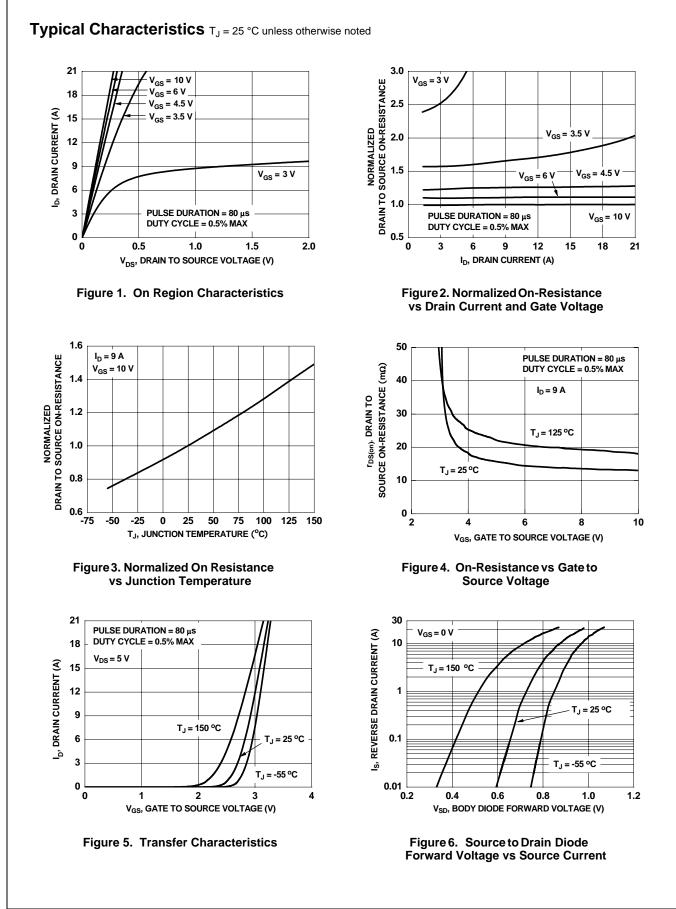
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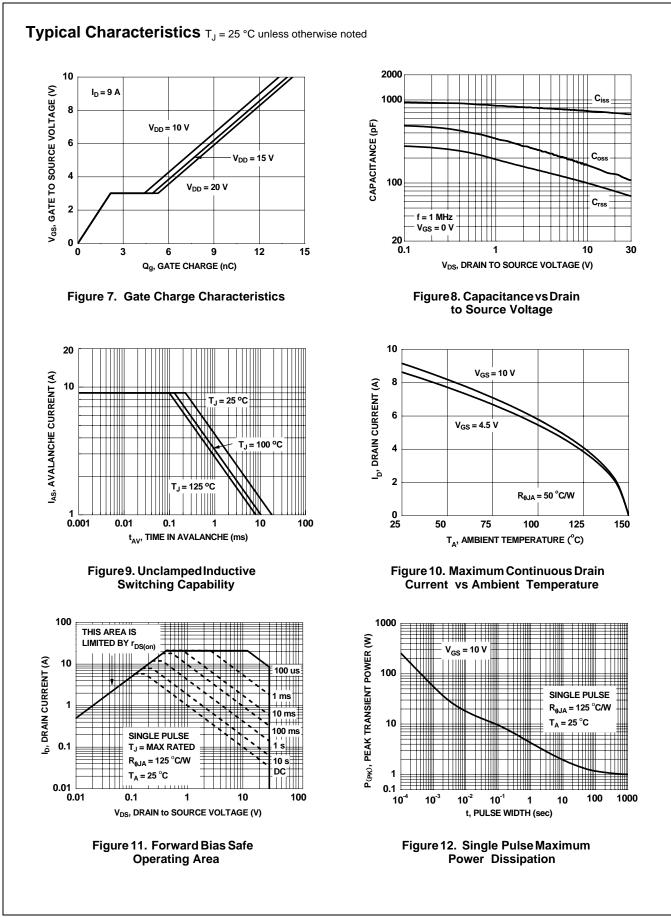
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nC

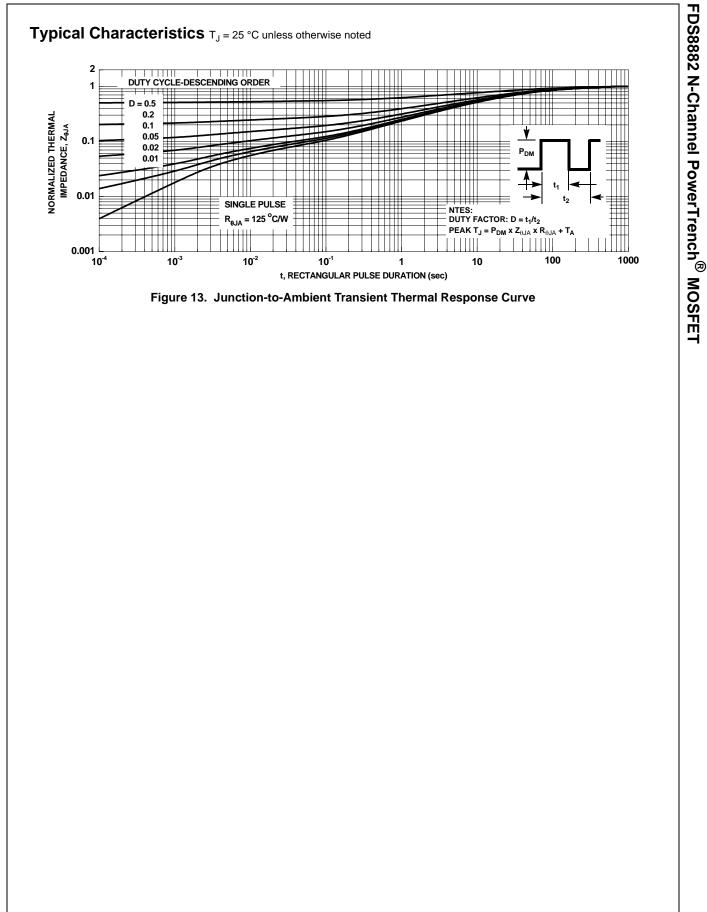
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FDS8882 N-Channel PowerTrench[®] MOSFET





FDS8882 N-Channel PowerTrench[®] MOSFET





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